

Product data sheet

## 1. General description

P-channel enhancement mode MOSFET in an LFPAK56 (Power SO8) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

This product has been designed and qualified to AEC-Q101 standard for use in high-performance automotive applications such as reverse battery protection.

## 2. Features and benefits

- High thermal power dissipation capability
- Suitable for thermally demanding environments due to 175 °C rating
- Trench MOSFET technology
- AEC-Q101 qualified

## 3. Applications

- Reverse battery protection
- Power management
- High-side loadswitch
- Motor drive

## 4. Quick reference data

Table 1. Quick r	reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-30	V
V <sub>GS</sub>	gate-source voltage		[1]	-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>mb</sub> = 25 °C		-	-	-67	A
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C		-	-	106	W
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -11 A; T <sub>j</sub> = 25 °C		-	8	12	mΩ

[1]  $V_{GS}$  = -20 V/+5 V according AEC-Q101 at T<sub>j</sub> = 175 °C;  $V_{GS}$  = -20 V/+20 V according AEC-Q101 at T<sub>j</sub> = 150 °C

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30 V, P-channel Trench MOSFET

## 5. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	D
2	S	source		
3	S	source		G-UP
4	G	gate		S S
mb	D	mounting base; connected to drain	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	017aaa094

## 6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BUK6Y12-30P	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669			

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BUK6Y12-30P	6Y1230P

## 8. Limiting values

 Table 5. Limiting values

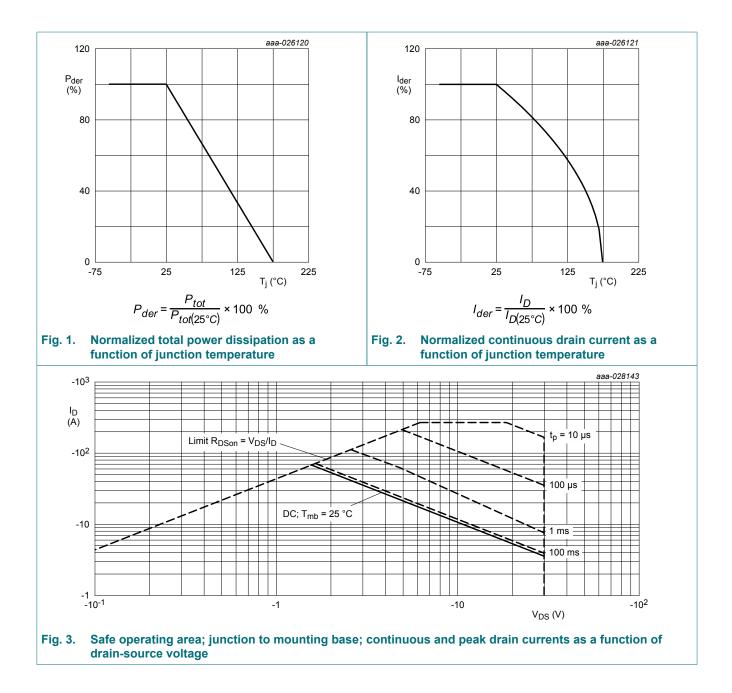
 In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-30	V
V <sub>GS</sub>	gate-source voltage	_	[1]	-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>mb</sub> = 25 °C		-	-67	А
		V <sub>GS</sub> = -10 V; T <sub>mb</sub> = 100 °C		-	-48	А
I <sub>DM</sub>	peak drain current	single pulse; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$		-	-269	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C		-	106	W
Tj	junction temperature			-55	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C
Source-drain	diode					
Is	source current	T <sub>mb</sub> = 25 °C		-	-67	А
I <sub>SM</sub>	peak source current	single pulse; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$		-	-269	А
ESD maximu	m rating					
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ	[2]	-	800	V
Avalanche ru	ıggedness				·	
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$V_{sup} \le -30 \text{ V}; V_{GS} = -10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $I_D = -11 \text{ A}; \text{ DUT in avalanche (unclamped)}$		-	4.4	mJ

[1]  $V_{GS}$  = -20 V/+5 V according AEC-Q101 at T<sub>j</sub> = 175 °C;  $V_{GS}$  = -20 V/+20 V according AEC-Q101 at T<sub>j</sub> = 150 °C [2] Measured between all pins.

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## 9. Thermal characteristics

#### Table 6. Thermal characteristics Symbol Parameter Conditions Unit Min Тур Max thermal resistance 1.1 1.4 K/W $R_{th(j-mb)}$ \_ from junction to mounting base aaa-028144 10 Z<sub>th(j-mb)</sub> (K/W) T duty cycle = 0.9 1 0.70 50 0.30 .10 10<sup>-1</sup> 0.05 0.02 0.01 10<sup>-2</sup> 10<sup>-5</sup> 10-4 10<sup>-3</sup> 10<sup>-2</sup> 10<sup>-1</sup> 1 t<sub>p</sub> (s) Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

## **10. Characteristics**

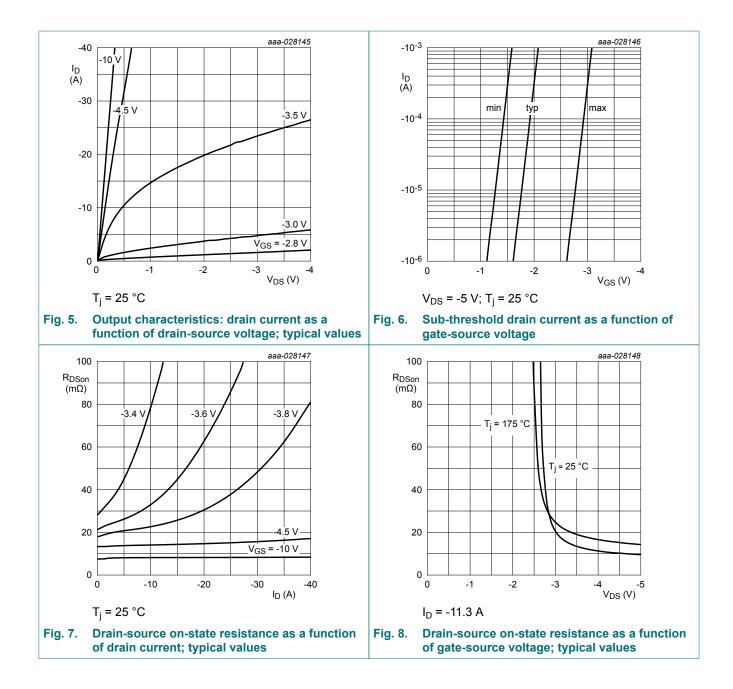
#### Table 7. Characteristics

 $T_i = 25 \ ^{\circ}C \ unless \ otherwise \ specified$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = -250 μA; V <sub>GS</sub> = 0 V	-30	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D = -250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	-1.5	-2	-3	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = -30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-1	μA
		V <sub>DS</sub> = -30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C	-	-	-100	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V	-	-	100	nA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V	-	-	-100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -11 A; T <sub>j</sub> = 25 °C	-	8	12	mΩ
	resistance	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -11 A; T <sub>j</sub> = 175 °C	-	16	23	mΩ
		V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -7.5 A	-	10	27	mΩ
9 <sub>fs</sub>	forward transconductance	$V_{DS}$ = -10 V; I <sub>D</sub> = -2 A; T <sub>j</sub> = 25 °C	-	33	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	6.1	-	Ω
Dynamic ch	naracteristics		1			
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = -15 V; I <sub>D</sub> = -11 A; V <sub>GS</sub> = -10 V	-	52	60	nC
Q <sub>GS</sub>	gate-source charge	] [	-	7.9	-	nC
Q <sub>GD</sub>	gate-drain charge	]	-	6.6	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -15 V; f = 1 MHz; V <sub>GS</sub> = 0 V	-	2880	-	pF
C <sub>oss</sub>	output capacitance		-	493	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	317	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = -15 V; I <sub>D</sub> = -11 A; V <sub>GS</sub> = -10 V;	-	8	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega$	-	46	-	ns
t <sub>d(off)</sub>	turn-off delay time	] [	-	94	-	ns
t <sub>f</sub>	fall time		-	6	-	ns
Source-drai	in diode					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -67 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-0.7	-1.2	V
t <sub>rr</sub>	reverse recovery time	$I_{S} = -8 \text{ A}; \text{ d}I_{S}/\text{d}t = 100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$	-	31	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = -15 V; T <sub>j</sub> = 25 °C	-	20	-	nC

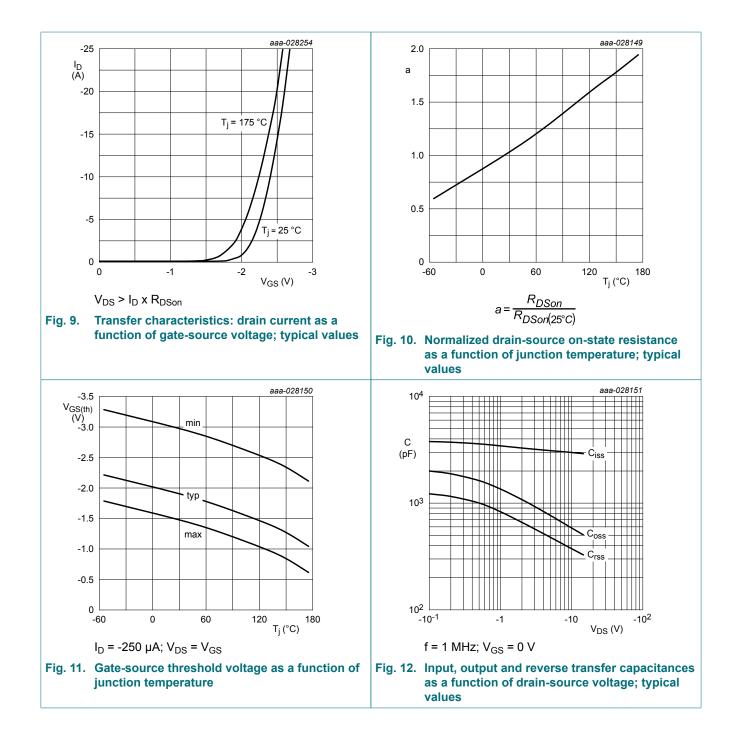
## BUK6Y12-30P

#### 30 V, P-channel Trench MOSFET



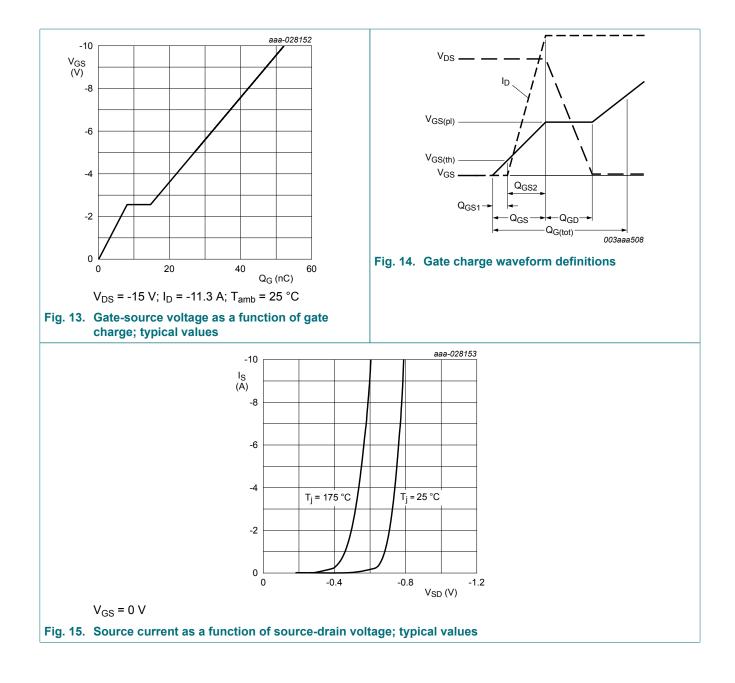
## BUK6Y12-30P

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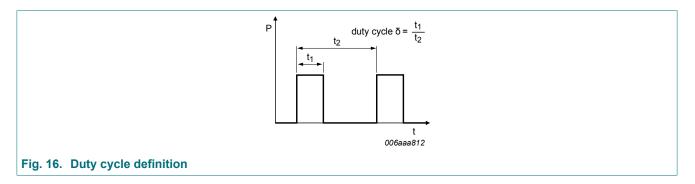


## BUK6Y12-30P

#### 30 V, P-channel Trench MOSFET



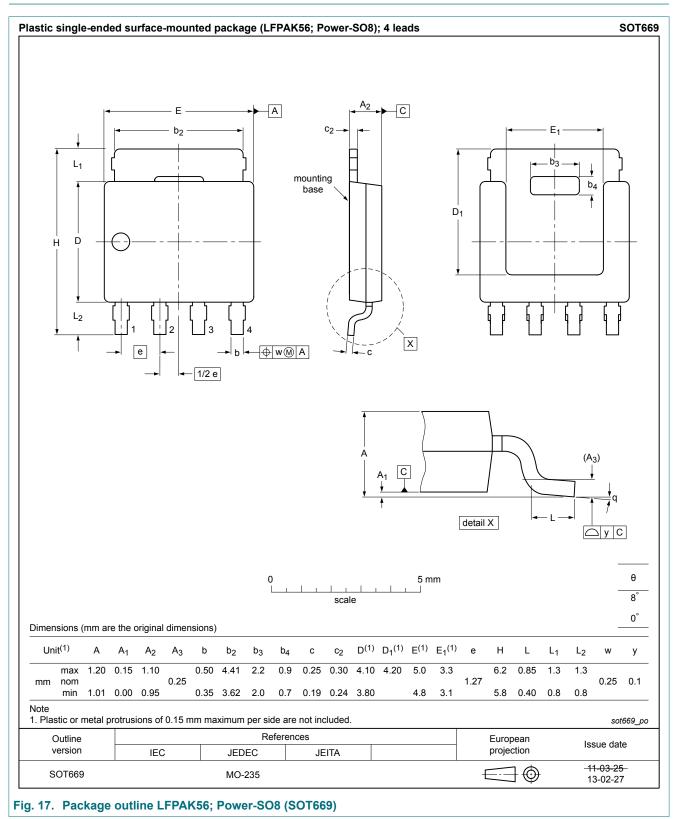
## 11. Test information



### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

## 12. Package outline



## **13. Revision history**

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BUK6Y12-30P v.2	20180607	Product data sheet	-	BUK6Y12-30P v.1		
Modifications:	Package description updated.					
BUK6Y12-30P v.1	20180316	Product data sheet	-	-		

#### 30 V, P-channel Trench MOSFET

## 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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